

30V P-Channel Enhancement Mode MOSFET

Voltage

Current -35 A

Features

• $R_{DS(ON)}$, $V_{GS}@-10V$, $I_D@-10A < 15.5m\Omega$

-30 V

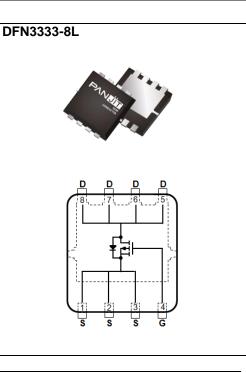
- $R_{DS(ON)}$, $V_{GS}@-4.5V$, $I_D@-6A < 23m\Omega$
- High switching speed
- Improved dv/dt capability
- Low gate charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN3333-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.03 grams

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage Gate-Source Voltage		V _{DS}	-30	V
		V _{GS}	<u>+</u> 20	V
Continuous Drain Current	T _C =25°C		-35	
	Tc=100°C	lD	-22	А
Pulsed Drain Current ^(Note 1)	Tc=25°C	I _{DM}	-140	
Power Dissipation	Tc=25°C	D-	30	24/
	Tc=100°C	PD -	11	W
Continuous Drain Current	T _A =25°C		-9.8	
	T _A =70°C	I _D	-7.8	— A
Power Dissipation	T _A =25°C	D	2.0	24/
Power Dissipation	T _A =70°C	PD -	1.3	W
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~150	°C
Typical Thermal Resistance ^(Note 4,5)	Junction to Case	R _{ejc}	4.2	
	Junction to Ambient	R _{0JA}	62.5	•C/W





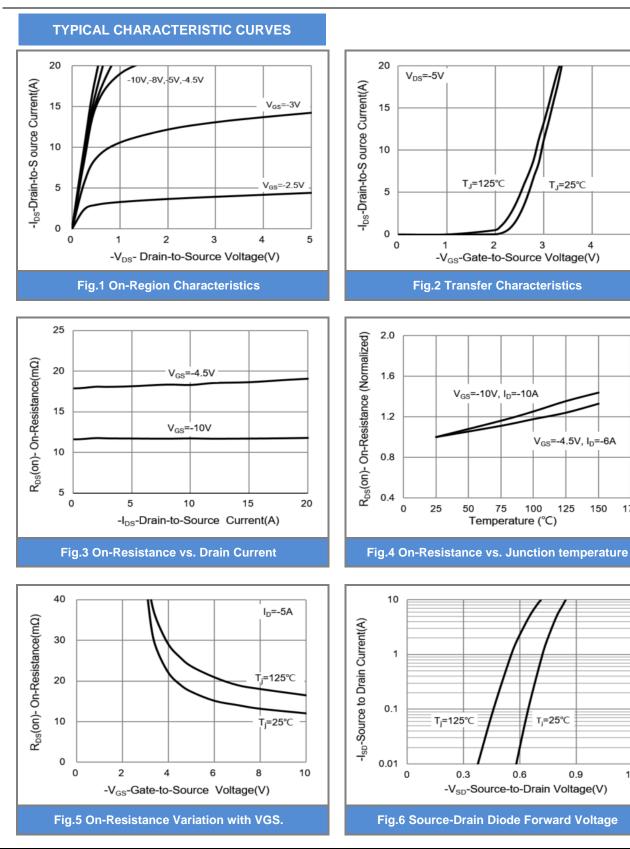
Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
	STWBUL	TEST CONDITION	IVIIIN.	ITF.	IVIAA.	
Static	51					
Drain-Source Breakdown Voltage	BV _{DSS} V _{GS} =0V,I _D =-250u	Vgs=0V,Id=-250uA	-30	-	-	v
Gate Threshold Voltage	VGS(th)	V _{DS} =V _{GS} ,I _D =-250uA	-1.0	-1.6	-2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V,I _D =-10A	-	12	15.5	mΩ
		V _{GS} =-4.5V,I _D =-6A	-	18	23	
Zero Gate Voltage Drain Current	IDSS	V _{DS} =-30V,V _{GS} =0V	-	-	-1.0	uA
Gate-Source Leakage Current	lgss	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic ^(Note 6)						
Total Gate Charge	Qg	V _{DS} =-15V, I _D =-8A, V _{GS} =-4.5V ^(Note 1,2)	-	15	-	nC
Gate-Source Charge	Q _{gs}		-	4	-	
Gate-Drain Charge	Q_{gd}		-	6	-	
Input Capacitance	Ciss	V _{DS} =-15V, V _{GS} =0V, f=1.0MHZ	-	1730	-	pF
Output Capacitance	Coss		-	180	-	
Reverse Transfer Capacitance	Crss		-	125	-	
Turn-On Delay Time	td _(on)	V _{DD} =-15V, I _D =-1A, V _{GS} =-10V, R _G =6Ω	-	9	-	
Turn-On Rise Time	tr		-	22	-	ns
Turn-Off Delay Time	td _(off)		-	60	-	
Turn-Off Fall Time	t _f		-	14	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	-35	А
Diode Forward Current	ls					
Diode Forward Voltage	V _{SD}	Is=-1A,V _{GS} =0V	-	-0.7	-1	V

NOTES :

- 1. Pulse width <300us, Duty cycle <2%.
- 2. Essentially independent of operating temperature typical characteristics.
- Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. R_{®JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





1.2

0.9

T**J=25°**C

125

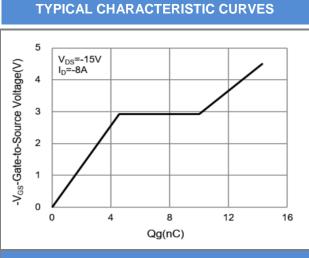
150

4

5

175







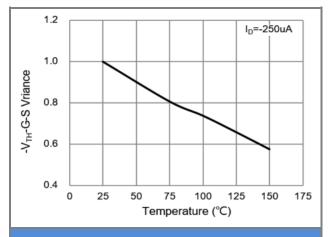
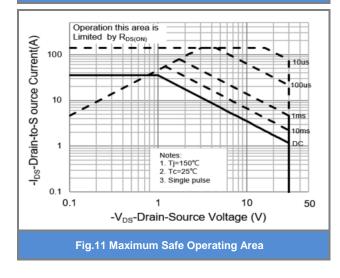
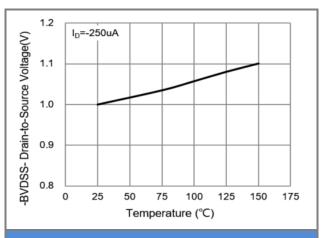


Fig.9 Threshold Voltage Variation with Temperature







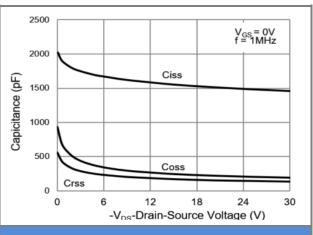
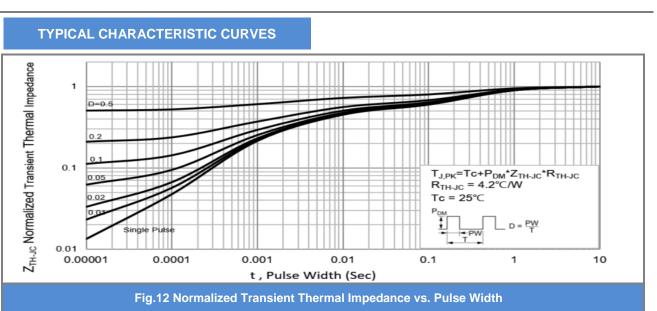


Fig.10 Capacitance vs. Drain-Source Voltage



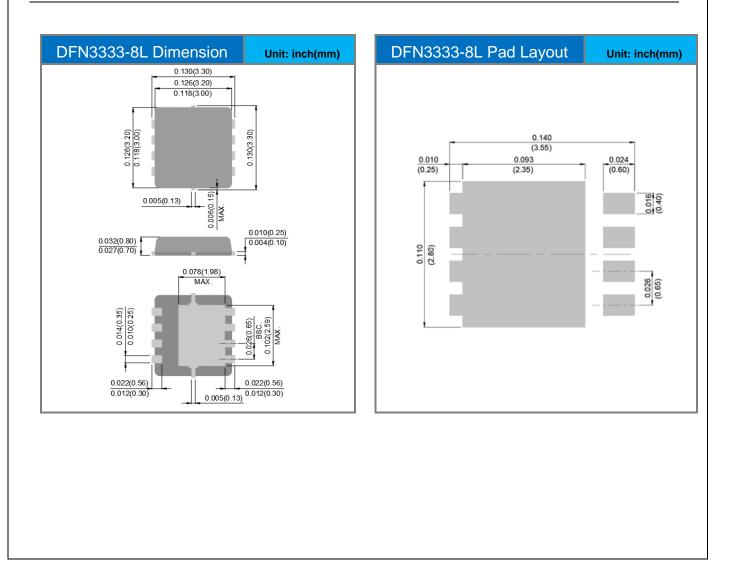




Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ4403P_R2_00001	DFN3333-8L	5K pcs / 13" reel	4403	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout





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